ETR0315 003

1A Low Dropout Positive Voltage Regulator

■GENERAL DESCRIPTION

The XB1117 series are 1A low dropout positive voltage regulators. Output voltage of the XB1117P series is fixed to 1.8V, 2.5V, 3.3V, and 5.0V. The XB1117K series' output voltage is adjustable by the external resistors. Please refer to the absolute maximum ratings for the difference between the rated input voltage of the XB1117P50 (Vout=5.0V) and XB1117P18, 25, 31, K12B. With the dropout voltage 1.2V (TYP.), output current can be generated up to 1A. The built-in overcurrent circuit and thermal protection circuit start to operate when either one of output put current reaches the current limit level or junction temperature reaches the temperature limit. The XB1117 series provide stable line and load regulation by using an input capacitor and an output capacitor (10μ F, tantalum). Package is available in SOT-223.

APPLICATIONS

- Highly efficient linear regulators
- ●5V ~ 3.3V DC / DC converter
- Battery charger
- Local power supply inside equipment
- Battery powered equipment

■FEATURES

Adjustable or Fixed Voltages : 1.8V, 2.5V, 3.3V, 5.0V, ADJ

Low Dropout Voltage : 1.2V @ IOUT=1A
Line Regulation (TYP.) : 0.04% (ADJ)
Load Regulation (TYP.) : 0.1% (ADJ)

Adjust Pin Current : Less than 120μ A (ADJ)

Over-current protection circuit built-in Thermal protection circuit built-in

Bi-polar transistors LDO

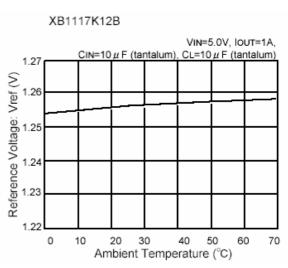
Output Voltage Accuracy : $\pm 1\%$ Output Current : Up to 1A
Package : SOT-223

■TYPICAL APPLICATION CIRCUIT

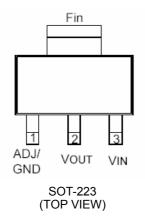
XB1117P Series VIN CIN=10 \(\mu \) F (Tantalum) XB1117F Series VIN Vout VSS CL=10 \(\mu \) F (Tantalum) XB1117K Series VIN VOUT ADJ CL=10 \(\mu \) F (Tantalum) R1 CL=10 \(\mu \) F (Tantalum) Vout=VREF x (1 + R2/R1) + IADJ x R2

■ TYPICAL PERFORMANCE CHARACTERISTICS

Reference Voltage vs. Ambient Temperature



■PIN CONFIGURATION



■PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTIONS
1	ADJ/GND	ADJ/Ground
2	Vout	Output
3	Vin	Input

The electrical potential of the package fin is the same as the VOUT pin.

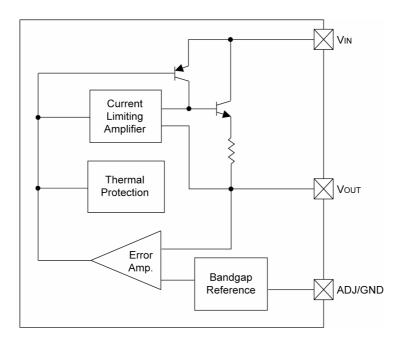
■PRODUCT CLASSIFICATION

Ordering Information

XB1117①23456

DESIGNATOR	DESCRIPTION	SYMBOL DESCRIPTION	
<u>(1)</u>	Tune of Degulators	Р	: Fixed Vouт type
	Type of Regulators	К	: Adjustable Vouт type
		181	: Fixed Vouт 1.80V (±1%)
	Outrot Valtage	251	: Fixed Vouт 2.50V (±1%)
234	Output Voltage & Accuracy	331	: Fixed Vouт 3.30V (±1%)
		501	: Fixed Vouт 5.00V (±1%)
		12B	: Adjustable Vo∪⊤ 1.25V (±1%)
5	Package	F	: SOT-223
(Device Orientation	R	: Embossed tape, standard feed
6	Device Orientation	L	: Embossed tape, reverse feed

■BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

XB1117P501

PARAMETER	SYMBOL	RATINGS	UNITS	
Input Voltage	VIN	10.0	V	
Thermal Resistance	θJc	15		
(Junction to Case)	0.30	10	°C/W	
Thermal Resistance	θ JA	160	C/VV	
(Junction to Ambient)	O JA	100		
Power Dissipation	PD	625	mW	
(ΔT=100°C)	I D	023	IIIVV	
Operating Temperature Range	Topr	0~+70		
Operating Junction Temperature Range	Tj	0 ~+125	°C	
Storage Temperature Range	Tstg	- 65 ~ + 150		
Lead Temperature	Tlead	260		

^{*}Stress above the listed absolute maximum rating may cause permanent damage to the device.

■ELECTRICAL CHARACTERISTICS

XB1117P501 Ta=25°C

PARAMETER	SYMBOL	CONDITIONS		MIN.	TYP.	MAX.	UNITS
Output Voltage	Vout	VIN=7.0V		4.950	5.000	5.050	V
Output Voltage	V 001	Iout=0A	*Over Temp.	4.900	5.000	5.100	V
Line Regulation	Δ VOUT1	7.0V≦VIN≦9.0V IOUT=0A	*Over Temp.	-	1	6	mV
Load Population	Δ V OUT2	VIN=7.0V		-	5.0	15.2	IIIV
Load Regulation	Δ ۷0012	0A≦Ioυτ≦1.0A	*Over Temp.	-	10.1	20.2	
Dropout Voltage	Vdif	ΔVout=±1%		-	1.2	1.4	V
Dropout voitage	Vair	0A≦Ioυτ≦1.0A	*Over Temp.	-	1.3	-	V
Current Limit	llim	7.0V≦VIN≦10.0V	*Over Temp.	1.0	1.5	-	Α
Supply Current	Iss	VIN=7.0V 0A≦IouT≦1.0A	*Over Temp.	-	6	13	mA
Temperature Coefficient	Тс	7.0V≦VIN≦10.0V 0A≦IouT≦1.0A		-	50	ı	ppm/°C
Temperature Stability	Ts	VIN=7.0V IOUT=100mA	*Over Temp.	-	0.5	-	%

^{*}Over Temp. = Over Temperature $(0 \sim +70^{\circ}C)$

^{**} The rated values of the XB1117P18 / 25 / 30 (VOUT=1.8V, 2.5V and 3.0V) and XB1117K type are different from that of the XB1117P50 (VOUT=5.0V).

■ ABSOLUTE MAXIMUM RATINGS

XB1117P181, P251, P331, K12B

PARAMETER	SYMBOL	RATINGS	UNITS
Input Voltage	VIN	7.0	V
Thermal Resistance (Junction to Case)	θ Jc	15	°C/W
Thermal Resistance (Junction to Ambient)	heta Ja	160	0/44
Power Dissipation (ΔT=100°C)	Pb	625	mW
Operating Temperature Range	Topr	0 ~ 70	
Operating Temperature Range	TJ	0 ~ 125	°C
Storage Temperature Range	Tstg	-65 ~ 150	C
Lead Temperature	TLEAD	260	

^{*}Stress above the listed absolute maximum rating may cause permanent damage to the device.

■ELECTRICAL CHARACTERISTICS

XB1117P181 T_J=25°C

PARAMETER	SYMBOL	CONDITIONS		MIN.	TYP.	MAX.	UNITS
Output Voltage	Vout	Vin=5.0V Iout=0A	*Over Temp.	1.782	1.800	1.818	٧
Line Regulation	ΔVout1	4.75V≦VIN≦7.0V IOUT = 0A		-	1.0	5.5	mV
Load Regulation	Δ Vout2	VIN=5.0V		-	1.80	18.2	mV
Load Regulation	Δ ۷0012	0A≦Iouт≦1.0A	*Over Temp.	-	3.70	22.0	IIIV
Dropout Voltage	Vdif	ΔVout=±1%		-	1.2	1.4	V
Dropout Voltage	Vuli	0A≦Iouт≦1.0A	*Over Temp.	-	1.3	-	V
Current Limit	llim	4.75V≦VIN≦7.0V	*Over Temp.	1.0	1.5	-	Α
Supply Current	Iss	Vin=5.0V 0A≦IouT≦1.0A	*Over Temp.	-	6	13	mA
Temperature Coefficient	Tc	4.75V≦VIN≦7.0V 0A≦IouT≦1.0A			50	-	°C
Temperature Stability	Ts	VIN=5.0V IOUT=100mA	*Over Temp.	-	0.5	-	%

^{*}Over Temp. = Over Temperature $(0 \sim +70^{\circ}C)$

XB1117P251 $T_{J} = 25^{\circ}C$

13-25					0 200		
PARAMETER	SYMBOL	CONDITIONS	CONDITIONS		IDARD V	ALUE	UNITS
PARAIVIETER	STIVIDOL	CONDITIONS		MIN.	TYP.	MAX.	UNITS
Output Voltage	Vout	VIN=5.0V		2.475	2.500	2.525	V
Output voltage	V001	Iout=0A	*Over Temp.	2.450	2.500	2.550	V
Line Regulation	Δ Vout1	4.75V≦VIN≦7.0V IOUT=0A		-	1.0	6.8	mV
Load Regulation	Δ Vout2	VIN=5.0V		-	2.5	25.3	mV
Load Regulation	Δ VOU12	0A≦Ioυτ≦1.0A	*Over Temp.	-	5.1	30.3	IIIV
Dropout Voltage	Vdif	ΔVouτ=±1%		-	1.2	1.4	V
Dropout voltage	vuii	0A≦Iouт≦1.0A	*Over Temp.	-	1.3	ı	V
Current Limit	llim	4.75V≦VIN≦7.0V	*Over Temp.	1.0	1.5	ı	Α
Supply Current	Iss	VIN=5.0V 0A≦IOUT≦1.0A	*Over Temp.	-	6	13	mA
Temperature Coefficient	Tc	4.75V≦VIN≦7.0V 0A≦IouT≦1.0A		-	50	1	ppm/ °C
Temperature Stability	Ts	VIN=5.0V IOUT=100mA	*Over Temp.	-	0.5	-	%

^{*}Over Temp. = Over Temperature $(0 \sim +70^{\circ}C)$

■ELECTRICAL CHARACTERISTICS (Continued)

XB1117P331

							1J =25°C
PARAMETER	SYMBOL	CONDITIONS		MIN.	TYP.	MAX.	UNITS
Output Voltage	Vout	VIN=5.0V		3.267	3.300	3.333	V
Output voltage	V 001	IOUT=0A	*Over Temp.	3.234	3.300	3.366	V
Line Regulation	Δ Vout1	4.75V≦VIN≦7.0V			1.0	4.5	
Line Regulation	Δ ۷0011	IOUT=0A		_	1.0	4.5	mV
Load Regulation	Δ Vout2	VIN=5.0V		-	3.4	10.0	IIIV
Load Regulation	Δ ۷0012	0A≦Iouт≦1.0V	*Over Temp.	-	6.7	13.4	
Dropout Voltage	Vdif	ΔVouτ=±1%		-	1.2	1.4	V
Dropout voltage	vuii	0A≦Iouт≦1.0A	*Over Temp.	-	1.3	-	٧
Current Limit	llim	4.75V≦VIN≦7.0V	*Over Temp.	1.0	1.5	-	Α
Supply Current	Iss	VIN=5.0V	*Over Temp.		6	13	mA
Зарріу Сапені	133	0A≦Iouт≦1.0A	Over remp.	_	0	13	ША
Temperature	Tc	4.75V≦VIN≦7.0V			50	_	ppm/°C
Coefficient	10	0A≦Iouт≦1.0A		_	30		рріпі С
Temperature Stability Ts	Ts	VIN=5.0V	*Over Temp.	_	0.5	_	%
Temperature otability	.0	IOUT=100mA	· O voi remp.		0.0		,0

^{*}Over Temp. = Over Temperature $(0 \sim +70^{\circ}C)$

XB1117K12B TJ=25°C

PARAMETER	SYMBOL	CONDITIONS	CONDITIONS		TYP.	MAX.	UNITS
Deference veltage	Vref	VIN=5.0V		1.238	1.250	1.262	V
Reference voltage	viei	IOUT=10mA	*Over Temp.	1.225	1.250	1.275	V
Line Regulation	Δ Vout1	4.75V≦VIN≦7.0V			0.04	0.20	%
Line Regulation	Δ ۷ Ο Ο Ι Ι	IOUT=0A		_	0.04	0.20	70
Load Regulation	Δ Vout2	VIN=5.0V		-	0.1	0.3	%
Load Regulation	Δ ۷0012	10mA≦Iouт≦1.0A	*Over Temp.	-	0.2	0.4	70
Dropout Voltage	Vdif	ΔVouτ=±1%		-	1.2	1.4	V
Diopout voitage	Vuli	10mA≦Iouт≦1.0A	*Over Temp.	-	1.3	-	V
Current Limit	llim	2.75A≦VIN≦7.0V	*Over Temp.	1.0	1.5	1	Α
Temperature	Tc	2.75V≦VIN≦7.0V			50		ppm/
Coefficient	10	10mA≦Iouт≦1.0A		_	50	-	°C
Adjust Pin Current	ladj	2.75V≦VIN≦7.0V			55	-	μΑ
Aujust Fill Cullent	IADJ	10mA≦Iouт≦1.0A	*Over Temp.	-	-	120	μΑ
Adjust Pin Current	ΔIADJ	2.75V≦VIN≦7.0V	*Over Temp.		0.2	5.0	μΑ
Change	ΔIADJ	10mA≦IouT≦1.0A	Over remp.	-	0.2	5.0	μΑ
Temperature Stability	Ts	VIN=5.0V	*Over Temp.		0.5		%
Temperature Stability	13	IOUT=100mA	Over lemp.	_	0.5		70
Minimum Load Current	Іоит	Vout=5.0V		-	-	10	mA

^{*}Over Temp. = Over Temperature $(0 \sim +70^{\circ}C)$

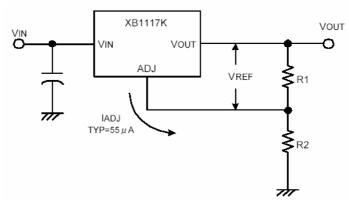
■ OPERATIONAL EXPLANATION

1. Output voltage adjustment

The XB1117 series provide a stable output by comparing the output voltage to an internal reference voltage. With the adjustable XB1117K type, a 1.25V reference voltage (VREF) is fixed between the Vout pin and the ADJ pin and the external resistors R1 and R2 are used to set the output voltage. The resistance values of R1 and R2 should be set so as to provide a minimum load current of 10mA. The output voltage is given by the following equation.

VOUT=VREF(1+R2/R1)+IADJ x R2

The output voltage of the XB1117P type is internally fixed to 1.8V, 2.5V, 3.3V, and 5.0V so external resistors are not necessary.



2. Stability and load regulation

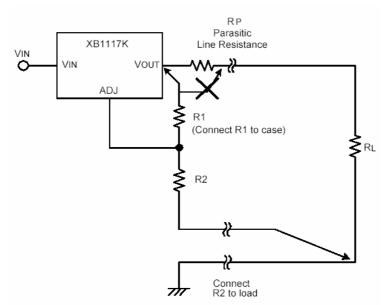
The XB1117 series requires a load capacitor between the Vout pin and the GND pin to provide phase compensation thereby ensuring stability of the output voltage. Either a tantalum capacitor of more than $10 \,\mu$ F (TYP.) or an aluminum electrolytic capacitor of more than $50 \,\mu$ F (TYP.) should be connected.

(Note: The capacitor's ESR value should not exceed 0.5Ω .)

The output capacitor does not have a theoretical upper limit so increasing its value will increase stability. CL=100 μ F or more is typical for high current regulator design.

In order to avoid any reductions in output voltage accuracy with the XB1117K type, we recommend not to place a parasitic resistor (Rp) between the Vout pin and the divider resistor R1. The parasitic resistor (Rp) does not influence the output however if the divider resistor R1 is directly connected to the Vout pin.

With the XB1117P type, although external resistor (R1) is internally connected to the VouT pin, stability can be maintained by not wiring a parasitic resistor to the GND pin.



■ OPERATIONAL EXPLANATION (Continued)

3. Thermal protection

XB1117 series has thermal protection which limits junction temperature to 150°C. However, device functionally is only guaranteed to a maximum junction temperature of + 125°C. The power dissipation and junction temperature for the XB1117 series are given by;

 $PD=(VIN-VOUT) \times IOUT$ $TJ=TA+(PD \times \theta JA)$

NOTE: TJ must not exceed 125°C.

4. Current limit protection

XB1117 series is protected against overload conditions. Current protection is triggered at 1.5A (TYP.).

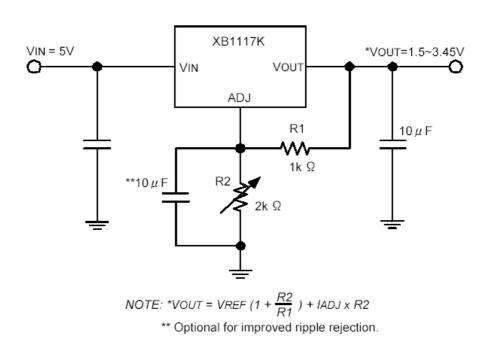
5. Thermal consideration

The XB1117 series contain thermal limiting circuitry designed to protect itself from over-temperature conditions. Even for normal load conditions, maximum junction temperature ratings must not be exceeded. As mentioned in thermal protection section, we need to consider all sources of thermal resistance between junction and ambient. It includes junction-to-case, case-to-heat-sink interface and heat sink thermal resistance itself.

Junction-to-case thermal resistance is specified from the IC junction to the bottom of the case directly below the die. Proper mounting is required to ensure the best possible thermal flow from this area of the package to the heat sink. The case of all devices in this product series is electrically connected to the output. Therefore, if the case of the device is not electrically isolated, a thermally conductive spacer is recommended.

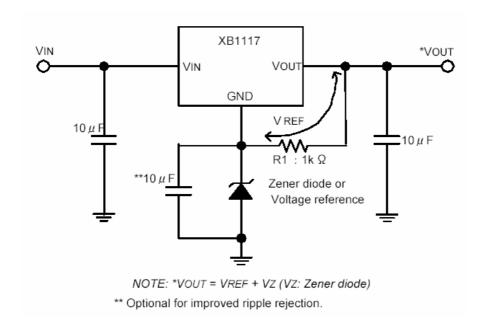
■APPLICATION CIRCUITS

Adjustable Output Voltage

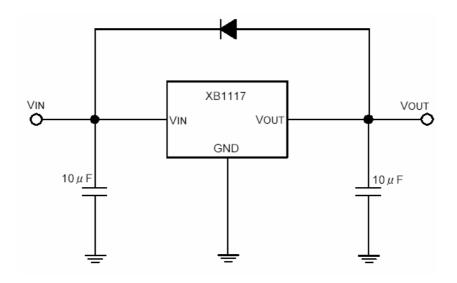


■APPLICATION CIRCUITS (Continued)

Regulator with reference voltage

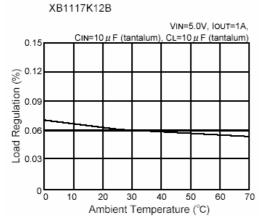


Regulator with reverse diode protection

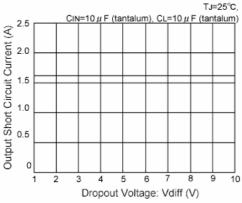


■TYPICAL PERFORMANCE CHARACTERISTICS

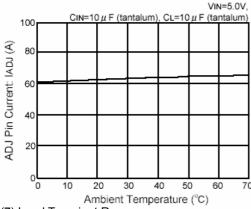
(1) Load Regulation vs. Ambient Temperature



(3) Output Short Circuit Current vs. Dropout Voltage XB1117P331

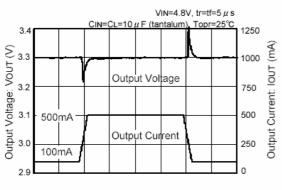


(5) Adjust Pin Current vs. Ambient Temperature XB1117K12B



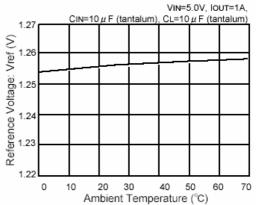
(7) Load Transient Response



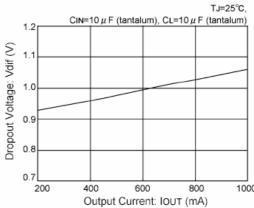


Time (20 µ s/div.)

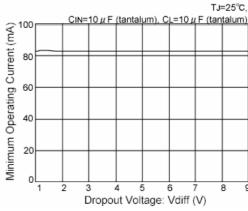
(2) Reference Voltage vs. Ambient Temperature XB1117K12B



(4) Dropout Voltage vs. Output Current XB1117P331

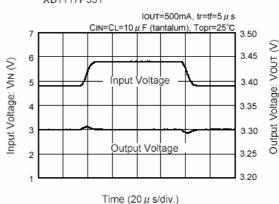


(6) Supply Current vs. Dropout Voltage XB1117P331



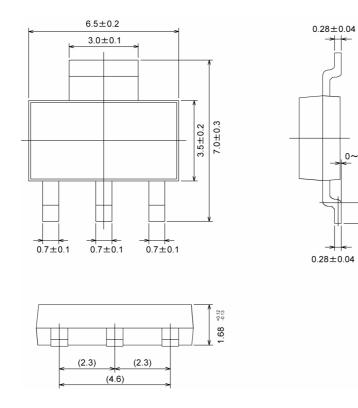
(8) Line Transient Response

XB1117P331



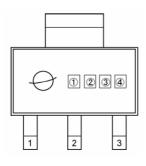
■ PACKAGING INFORMATION

●SOT-223



■MARKING RULE

●SOT-223



SOT-223 (TOP VIEW)

① Represents product series

MARK	PRODUCT SERIES	
В	XB1117xxxxFx	

2 Represents fixed or adjustable output voltage

0~0.1

MARK	PRODUCT SERIES
К	XB1117KxxxFx
Р	XB1117PxxxFx

3 Represents output voltage

MARK	OUTPUT VOLTAGE (V)	PRODUCT SERIES
В	ADJ	XB1117K12BFx
K	1.8	XB1117P181Fx
Т	2.5	XB1117P251Fx
2	3.3	XB1117P331Fx
M	5.0	XB1117P501Fx

4 Represents production lot number

0 to 9, A to Z repeated. (G, I, J, O, Q, W are excepted.)

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